Small switching (30V, 0.1A) UM5K1N

Features

- 1) Two 2SK3018 transistors in a single UMT package.
- 2) Mounting cost and area can be cut in half.
- 3) Low on-resistance.
- Low voltage drive (2.5V) makes this device ideal for portable equipment.
- 5) Easily designed drive circuits.

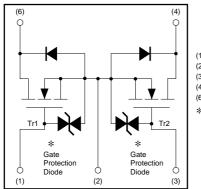
Applications

Interfacing, switching (30V, 100mA)

Structure

Silicon N-channel MOSFET

•Equivalent circuit



(1) Tr1 Gate
(2) Source
(3) Tr2 Gate
(4) Tr2 Drain

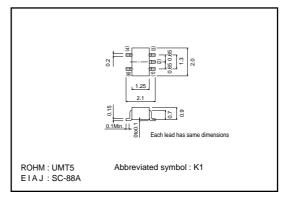
(4) Tr2 Drain (6) Tr1 Drain

* A protection diode has been built in between the gate and the source to protect against static electricity when the product is in use. Use the protection circuit when rated voltagesare exceeded.

Packaging specifications

Туре	Package	Taping
	Code	TR
	Basic ordering unit (pieces)	3000
UM5K1N		0

•External dimensions (Units : mm)





Transistors

Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		Vdss	30	V
Gate-source voltage		Vgss	±20	V
Drain current	Continuous	lo	100	mA
Drain current	Pulsed	Idp*1	200	mA
Reverse drain	Continuous	ldr	100	mA
current	Pulsed	Idrp*1	200	mA
Total power dissipation (Tc=25°C)		Pd ^{*2}	150	mW
Channel temperature		Tch	150	°C
Storage temperature		Tstg	-55~+150	°C

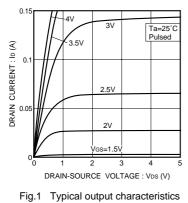
*1 Pw≤10μs, Duty cycle≤50%

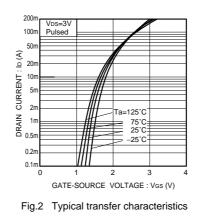
*2 With each pin mounted on the recommended lands.

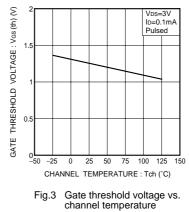
•Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Gate-source leakage	lgss	-	-	±1	μA	Vgs=±20V, Vds=0V
Drain-source breakdown voltage	V(BR)DSS	30	-	-	V	ID=10μA, Vgs=0V
Zero gate voltage drain current	IDSS	-	-	1.0	μA	VDS=30V, VGS=0V
Gate threshold voltage	VGS(th)	0.8	-	1.5	V	Vps=3V, Ip=100µA
Static drain-source on-stage	RDS(on)	-	5	8	Ω	ID=10mA, VGs=4V
resistance	RDS(on)	-	7	13	Ω	ID=1mA, VGs=2.5V
Forward transfer admittance	Yfs	20	-	-	mS	ID=10mA, VDS=3V
Input capacitance	Ciss	-	13	-	pF	VDS=5V
Output capacitance	Coss	-	9	-	pF	Vgs=0V
Reverse transfer capacitance	Crss	-	4	-	pF	f=1MHz
Turn-on delay time	td(on)	-	15	-	ns	ID=10mA, VDD≒5V
Rise time	tr	-	35	-	ns	Vgs=5V
Turn-off delay time	td(off)	-	80	-	ns	R∟=500Ω
Fall time	tr	I	80	-	ns	Rgs=10Ω

•Electrical characteristic curves



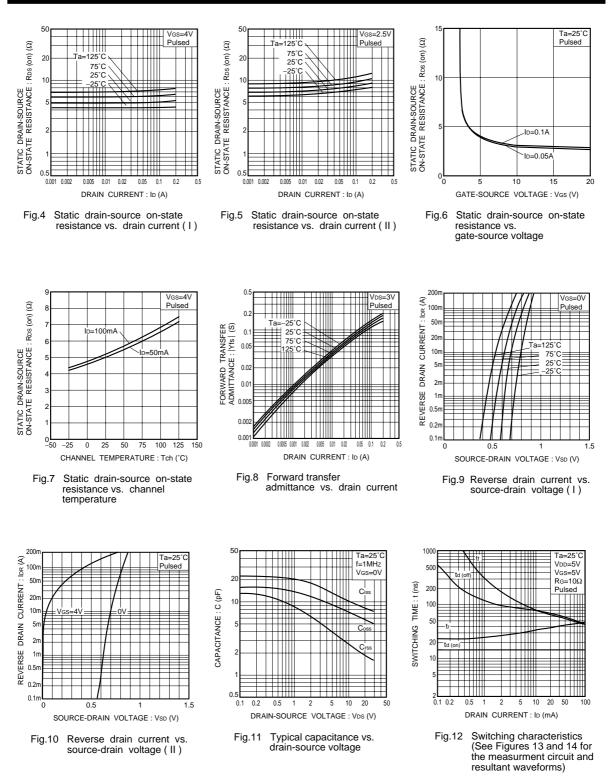




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UM5K1N

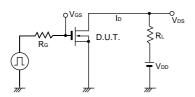
Transistors



rohm

Transistors

•Switching characteristics measurement circuit



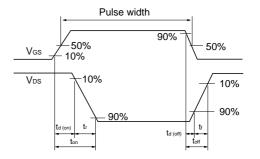


Fig.13 Switching time measurement circuit

Fig.14 Switching time waveforms



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